CLL914

HIGH SPEED SWITCHING DIODE



SOD-80 CASE



DESCRIPTION:

The CENTRAL SEMICONDUCTOR CLL914 type is an ultra-high speed silicon switching diode manufactured by the epitaxial planar process, in a hermetically sealed glass surface mount package, designed for high speed switching applications.

Marking code: Cathode Band.

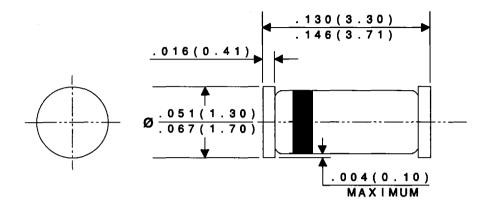
MAXIMUM RATINGS (TA=25°C)

	SYMBOL		UNITS
Continuous Reverse Voltage	v_R	75	V
Peak Repetitive Reverse Voltage	V _{RRM}	100	V
Continuous Forward Current	1 _F	250	mA
Peak Repetitive Forward Current	IFRM	250	mA
Forward Surge Current, tp=1 μsec.	^I FSM	4000	mA
Forward Surge Current, tp=1 sec.	¹ FSM	1000	mA
Power Dissipation	PD	500	mW
Operating and Storage	_		
Junction Temperature	T _J ,T _{stg}	-65 to +200	°C
Thermal Resistance	ΘJΑ	350	°C/W

ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
V_{BR}	I _R =100μA	100		V
l _R	V _R =20V		25	nΑ
I _R	V _R =75V		5.0	μΑ
٧F	I _E =10mA		1.0	V
CT	V _R =0, f=1 MHz		4.0	pF
t _{rr}	$I_R=I_F=10$ mA, $R_L=100\Omega$, Rec. to	1.0mA	4.0	ns

All dimensions in inches (mm).



DATA SHEET